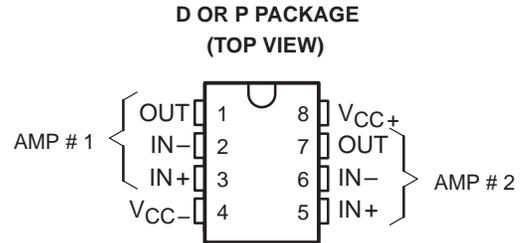


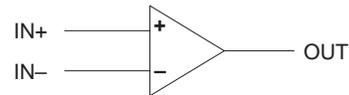
# RC4559 DUAL HIGH-PERFORMANCE OPERATIONAL AMPLIFIER

SLOS074 – D2785, OCTOBER 1983 — REVISED JUNE 1988

- **Matched Gain and Offset Between Amplifiers**
- **Unity-Gain Bandwidth . . . 3 MHz Min**
- **Slew Rate . . . 1.5 V/ns Min**
- **Low Equivalent Input Noise Voltage**  
2  $\mu$ V/Hz Max (20 Hz to 20 kHz)
- **No Frequency Compensation Required**
- **No Latch Up**
- **Wide Common-Mode Voltage Range**
- **Low Power Consumption**
- **Designed to be Interchangeable with Raytheon RC4559**



**symbol (each amplifier)**



**AVAILABLE OPTIONS**

SYMBOLIZATION		OPERATING TEMPERATURE RANGE	$V_{IO}$ max at 25°C
DEVICE	PACKAGE SUFFIX		
RC4559	D, P	-0°C to 70°C	6 mV

The D packages are available taped and reeled. Add the suffix R to the device type when ordering. (i.e., RC4559DR)

**description**

The RC4559 is a dual high-performance operational amplifier. The high common-mode input voltage and the absence of latch-up make this amplifier ideal for low-noise signal applications such as audio preamplifiers and signal conditioners. This amplifier features a guaranteed dynamic performance and output drive capability that far exceeds that of the general-purpose type amplifiers.

The RC4559 is characterized for operation from 0°C to 70°C.

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)**

Supply voltage $V_{CC+}$ (see Note 1)	18 V
Supply voltage $V_{CC-}$ (see Note 1)	-18 V
Differential input voltage (see Note 2)	$\pm 30$ V
Input voltage (any input, see Notes 1 and 3)	$\pm 15$ V
Duration of output short-circuit to ground, one amplifier at a time (see Note 4)	unlimited
Continuous total dissipation	500 mW
Operating free-air temperature range	0°C to 70°C
Storage temperature range	-65°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

- NOTES: 1. All voltage values, unless otherwise noted, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between  $V_{CC+}$  and  $V_{CC-}$ .
2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
4. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

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electrical characteristics at specified free-air temperature,  $V_{CC+} = 15\text{ V}$ ,  $V_{CC-} = -15\text{ V}$

PARAMETER		TEST CONDITIONS†	$T_A$ ‡	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage	$V_O = 0$	25°C		2	6	mV
			Full Range			7.5	
$I_{IO}$	Input offset current	$V_O = 0$	25°C		5	100	nA
			Full range			200	
$I_{IB}$	Input bias current	$V_O = 0$	25°C		40	250	nA
			Full range			500	
$V_I$	Input voltage range		25°C	±12	±13		V
$V_{OM}$	Maximum peak output voltage swing	$R_L \geq 3\text{ k}\Omega$	25°C	±12	±13		V
		$R_L = 600\ \Omega$	25°C	±9.5	±10		
		$R_L \geq 2\text{ k}\Omega$	Full range	±10			
$V_I$	Input voltage range	$V_O = \pm 10\text{ V}$ , $R_L = 2\text{ k}\Omega$	25°C	20	300		V/mV
			Full range	15			
$B_{OM}$	Maximum output-swing bandwidth	$V_{OPP} = 20\text{ V}$ , $R_L = 2\text{ k}\Omega$	25°C	24	32		kHz
$B_1$	Unity-gain bandwidth		25°C	3	4		MHz
$r_i$	Input resistance		25°C	0.3	1		M $\Omega$
CMRR	Common-mode rejection ratio	$V_O = 0$	25°C	80	100		dB
$k_{SVS}$	Supply voltage sensitivity ( $\Delta V_{IO}/\Delta V_{CC}$ )	$V_O = 0$	25°C		10	75	$\mu\text{V}/\text{V}$
$V_n$	Equivalent input noise voltage (closed loop)	$A_{VD} = 100$ , $R_S = 1\text{ k}\Omega$ , $f = 20\text{ Hz to } 20\text{ kHz}$	25°C		1.4	2	$\mu\text{V}$
$I_n$	Equivalent input noise current	$f = 20\text{ Hz to } 20\text{ kHz}$	25°C		25		pA
$I_{CC}$	Supply current (both amplifiers)	No load, No signal	25°C		3.3	5.6	mA
			0°C		4	6.6	
			70°C		3	5	
$V_{O1}/V_{O2}$	Crosstalk attenuation	$A_{VD} = 100$ , $R_S = 1\text{ k}\Omega$ , $f = 10\text{ kHz}$	25°C		90		dB

† All characteristics are specified under open-loop operation, unless otherwise noted.

‡ Full range operating free-air temperature range is 0°C to 70°C.

matching characteristics at  $V_{CC+} = 15\text{ V}$ ,  $V_{CC-} = -15\text{ V}$ ,  $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage	$V_O = 0$		±0.2		mV
$I_{IO}$	Input offset current	$V_O = 0$		±7.5		nA
$I_{IB}$	Input bias current	$V_O = 0$		±15		nA
$A_{VD}$	Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$ , $R_L = 2\text{ k}\Omega$		±1		dB

operating characteristics,  $V_{CC+} = 15\text{ V}$ ,  $V_{CC-} = -15\text{ V}$ ,  $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_r$	Rise time	$V_I = 20\text{ mV}$ , $R_L = 2\text{ k}\Omega$ , $C_L = 100\text{ pF}$		80		$\mu\text{s}$
	Overshoot			18%		
SR	Slew rate at unity gain	$V_I = 10\text{ mV}$ , $R_L = 2\text{ k}\Omega$ , $C_L = 100\text{ pF}$	1.5	2		V/ $\mu\text{s}$



**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
RC4559D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
RC4559DR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
RC4559P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**None:** Not yet available Lead (Pb-Free).

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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